## CLAIMS

What is claimed is:

1	1.	An integrated circuit comprising:
2		one or more functional blocks to perform one or
3	more	functions; and
4		an on-chip frequency compensation circuit including
5		a selectively enabled reliability oscillator
6		to generate a reference oscillating signal,
7		a clocked reliability oscillator to generate
8		an AC degraded oscillating signal, and
9		a compare circuit coupled to the reliability
10		oscillators, the compare circuit to compare the
11		oscillating signals and to generate a frequency
12		compensation signal in response to the comparison
13		being greater than a predetermined threshold.
1	2.	The integrated circuit of claim 1, wherein
2		the on-chip frequency compensation circuit further
3	inclu	ıdes
4		a first counter coupled between the
5		selectively enabled reliability oscillator and the
6		compare circuit, the first counter to generate a
7		reference count;

8	a second counter coupled between the clocked
9	reliability oscillator and the compare circuit, the
10	second counter to generate a dynamic count; and
11	the compare circuit to compare the reference
12	count with the dynamic count.

3. The integrated circuit of claim 2, wherein the on-chip frequency compensation circuit further includes

a first prescaler coupled between the selectively enabled reliability oscillator and the first counter, the first prescaler to divide by N the number of oscillations in an oscillating signal from the selectively enabled reliability oscillator; and

a second prescaler coupled between the dynamic reliability oscillator and the second counter, the second prescaler to divide by N the number of oscillations in an oscillating signal from the dynamic reliability oscillator.

4. The integrated circuit of claim 1, wherein the on-chip frequency compensation circuit further includes

a static reliability oscillator to generate a DC bias degraded oscillating signal.

1	5.	The integrated circuit of claim 4, wherein
2		the on-chip frequency compensation circuit further
3	inclu	des
4		a first counter coupled between the
5		selectively enabled reliability oscillator and the
6		compare circuit, the first counter to generate a
7		reference count;
8		a second counter coupled between the clocked
9		reliability oscillator and the compare circuit, the
10		second counter to generate a dynamic count;
11		a third counter coupled between the static
12		reliability oscillator and the compare circuit, the
13		third counter to generate a static count; and
14		the compare circuit to compare the reference
15		count with the dynamic count and the reference
16		count with the static count.
1	6.	The integrated circuit of claim 5, wherein
2		the on-chip frequency compensation circuit further
3	inclu	des
4		a first prescaler coupled between the
5		selectively enabled reliability oscillator and the
6		first counter, the first prescaler to divide by N
7		the number of oscillations in an oscillating signal

from the selectively enabled reliability

oscillator;

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10		a second prescaler coupled between the dynamic
11		reliability oscillator and the second counter, the
12		second prescaler to divide by N the number of
13		oscillations in an oscillating signal from the
14		dynamic reliability oscillator; and
15		a third prescaler coupled between the static
16		reliability oscillator and the third counter, the
17		third prescaler to divide by N the number of
18		oscillations in an oscillating signal from the
19		static reliability oscillator.
1	7.	The integrated circuit of claim 1, wherein

- 7. The integrated circuit of claim 1, wherein the integrated circuit is a microprocessor.
- 1 8. An integrated circuit comprising: 2 one or more functional blocks; and 3 an on-chip frequency compensation circuit including 4 a selectively enabled reliability oscillator 5 to generate a reference oscillating signal, 6 a static reliability oscillator to generate a 7 DC bias degraded oscillating signal, and 8 a compare circuit coupled to the reliability 9 oscillators, the compare circuit to compare the 10 oscillating signals and to generate a frequency 11 compensation signal in response to the comparison

being greater than a predetermined threshold.

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1	9.	The integrated circuit of claim 8, wherein
2		the on-chip frequency compensation circuit further
3	incl	udes
4		a first counter coupled between the
5		selectively enabled reliability oscillator and the
6		compare circuit, the first counter to generate a
7		reference count;
8		a second counter coupled between the static
9		reliability oscillator and the compare circuit, the
10		second counter to generate a static count; and
11		the compare circuit to compare the reference
12		count with the static count.
1	10.	The integrated circuit of claim 9, wherein
2		the on-chip frequency compensation circuit further
3	incl	udes
4		a first prescaler coupled between the
5		selectively enabled reliability oscillator and the
6		first counter, the first prescaler to divide by N
7		the number of oscillations in an oscillating signal
8		from the selectively enabled reliability
9		oscillator; and
10		a second prescaler coupled between the dynamic
11		reliability oscillator and the second counter, the
12		second prescaler to divide by N the number of

13		oscillations in an oscillating signal from the
14		static reliability oscillator.
1	11.	The integrated circuit of claim 8, wherein
2		the integrated circuit is a microprocessor.
1	12.	An integrated circuit comprising:
2		one or more functional blocks to perform one or
3	more	functions; and
4		an on-chip frequency compensation circuit including
5		a first reliability oscillator including a
6		selectively powered on ring oscillator to avoid
7		transistor degradation, the first reliability
8		oscillator to generate a reference oscillating
9		signal on a first oscillation output,
10		a second reliability oscillator including a
11		constantly powered ring oscillator to experience
12		transistor degradation, the second reliability
13		oscillator to generate a degraded oscillating
14		signal on a second oscillation output,
15		a first counter having an input to couple to
16		the first oscillation output, the first counter to
17		generate a reference count on a first count output,
18		and
19		a second counter having an input to couple to
20		the second oscillation output, the second counter

21	to generate	a	degraded	count	on	a	second	count
22	output.							

1	13. The integrated circuit of claim 12, wherein
2	the on-chip frequency compensation circuit further
3	includes
4	a first prescaler coupled between the first
5	reliability oscillator and the first counter, the
6	first prescaler to divide by N the number of
7	oscillations in the reference oscillating signal;
8	and
9	a second prescaler coupled between the second
10	reliability oscillator and the second counter, the

14. The integrated circuit of claim 12, wherein
the second reliability oscillator includes a
constantly powered static ring oscillator to
experience DC static transistor degradation, the
degraded oscillating signal is an DC bias degraded
oscillating signal on the second oscillation
output, and the degraded count is a static count.

second prescaler to divide by N the number of

oscillations in the degraded oscillating signal.

1 15. The integrated circuit of claim 12, wherein
2 the second reliability oscillator includes a
3 constantly powered clocked ring oscillator to

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4		experience AC dynamic transistor degradation, the
5		degraded oscillating signal is an AC degraded
6		oscillating signal on the second oscillation
7		output, and the degraded count is a dynamic count.
1	16.	The integrated circuit of claim 15, wherein
2		the on-chip frequency compensation circuit further
3	incl	udes
4		a third reliability oscillator including a
5		constantly powered static ring oscillator to
6		experience DC static transistor degradation, the
7		third reliability oscillator to generate a DC bias
8		degraded oscillating signal on a third oscillation
9		output, and
10		a third counter having an input to couple to
11		the third oscillation output, the third counter to
12		generate a static count on a third count output.
1	17.	The integrated circuit of claim 16, wherein
2		the on-chip frequency compensation circuit further
3	incl	udes
4		a first prescaler coupled between the first
5		reliability oscillator and the first counter, the
6		first prescaler to divide by N the number of
7		oscillations in the reference oscillating signal,
8		a second prescaler coupled between the second
9		reliability oscillator and the second counter, the

10	second prescaler to divide by N the number of
11	oscillations in the dynamic oscillating signal, and
12	a third prescaler coupled between the third
13	reliability oscillator and the third counter, the
14	third prescaler to divide by N the number of
15	oscillations in the static oscillating signal.

- 18. The integrated circuit of claim 13, wherein
  the on-chip frequency compensation circuit further
  includes
  a state machine to start and stop the counting
- 19. The integrated circuit of claim 13, wherein

by the counters.

the first counter includes a count overflow output and a count enable input, the count overflow output being a stop signal is coupled to the count enable input to stop the first counter from counting further, and

the on-chip frequency compensation circuit further includes

a first synchronizer having an input coupled to the count overflow output and an output coupled to a count enable input of the second counter, the first synchronizer to synchronize the stop signal to stop the second counter from counting further.

1 20. The integrated circuit of claim 16, wherein

2	the first counter includes a count overflow output
3	and a count enable input, the count overflow output
4	being a stop signal is coupled to the count enable input
5	to stop the first counter from counting further, and
6	the on-chip frequency compensation circuit further
7	includes
8	a first synchronizer having an input coupled
9	to the count overflow output and an output coupled
10	to a count enable input of the second counter, the
11	first synchronizer to synchronize the stop signal
12	to stop the second counter from counting further,
13	and
14	a second synchronizer having an input coupled
15	to the count overflow output and an output coupled
16	to a count enable input of the third counter, the
17	second synchronizer to synchronize the stop signal

1 21. The integrated circuit of claim 12, wherein
2 a clock signal is coupled into a clock input of the
3 second reliability oscillator.

to stop the third counter from counting further.

- 1 22. The integrated circuit of claim 12, wherein 2 the integrated circuit is a microprocessor.
- 1 23. A method in an integrated circuit with functional
  2 blocks, the method comprising:

3	enabling measurement of ring oscillator frequencies
4	of a trio of ring oscillators;
5	measuring a first frequency of a first ring
6	oscillator having non-stressed transistors;
7	measuring a second frequency of a second ring
8	oscillator having stressed transistors;
9	comparing the first frequency with the second
10	frequency to determine a first measure of transistor

1 24. The method of claim 23, wherein 2 the stressed transistors of the second ring

oscillator are dynamically stressed transistors.

- The method of claim 23, wherein
  the stressed transistors of the second ring
  oscillator are statically stressed transistors.
- 26. The method of claim 25, further comprising
  measuring a third frequency of a third ring
  oscillator having dynamically stressed transistors; and
  comparing the first frequency with the third
  frequency to determine a second measure of transistor
  degradation.
- 1 27. The method of claim 23 further comprising:

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degradation.

- 2 performing one or more functions with the
- 3 functional blocks.
- 1 28. The method of claim 27, wherein
- 2 the functional blocks include an execution unit to
- 3 execute instructions; and
- 4 the integrated circuit is a microprocessor.
- 1 29. The method of claim 23, wherein
- 2 the first ring oscillator and the second ring
- 3 oscillator have substantially similar circuits.
- 1 30. The method of claim 29, wherein
- 2 the the second ring oscillator has degraded
- 3 transistors; and
- 4 the first ring oscillator has transistors without
- 5 degradation.
- 1 31. The method of claim 23, wherein
- 2 the comparing determines a new clock ratio,
- and if the new clock ratio is less than an initial
- 4 clock ratio multiplied by a guard band, then the new
- 5 clock ratio is output to a clock generator.
- 1 32. The method of claim 31, further comprising
- 2 generating a clock signal using the new clock
- 3 ratio.

2	an execution unit to execute instructions; and
3	an integrated on-chip frequency compensation
4	circuit including
5	a reference reliability oscillator to
6	selectively generate a reference oscillating
7	signal,
8	a degrading reliability oscillator to
9	selectively generate a degraded oscillating signal,
10	and
11	a measurement and comparison circuit coupled
12	to the reliability oscillators, the measurement and
13	comparison circuit to receive the reference
14	oscillating signal and the degrading oscillating
15	signal to generate a first measure of transistor
16	degradation, the measurement and comparison circuit
17	to receive the reference oscillating signal and the
18	DC degraded oscillating signal to generate a second
19	measure of transistor degradation.

33. A microprocessor integrated circuit comprising:

- 1 34. The microprocessor integrated circuit of claim 33,
  2 wherein
  - the degrading reliability oscillator is a dynamic reliability oscillator that selectively generates an AC degraded oscillating signal.

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1	35.	The	microprocessor	integrated	circuit	of	claim	33,
_	_	_						

wherein

the degrading reliability oscillator is a static reliability oscillator that selectively generates a DC degraded oscillating signal.

36. The microprocessor integrated circuit of claim 35, further comprising

a dynamic reliability oscillator to selectively generate an AC degraded oscillating signal, and

the measurement and comparison circuit to receive the reference oscillating signal and the AC degraded oscillating signal to generate a first measure of transistor degradation, the measurement and comparison circuit to receive the reference oscillating signal and the DC degraded oscillating signal to generate a second measure of transistor degradation.

37. The microprocessor integrated circuit of claim 36, wherein

the measurement and compare circuit further to compare the first measure of transistor degradation with the second measure of transistor degradation to determine a worst transistor degradation.

1	38. The microprocessor integrated circuit of claim 37
2	wherein
3	the measurement and compare circuit to generate a
4	frequency compensation signal in response to the worst
5	transistor degradation being greater than a
6	predetermined level.